

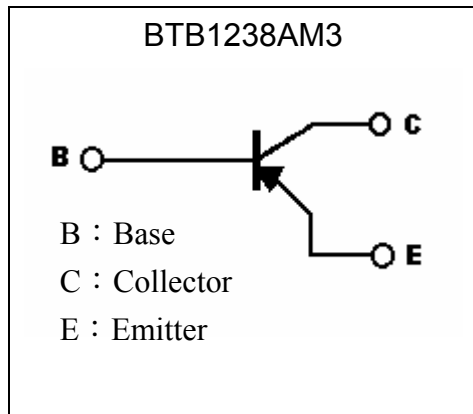
Silicon PNP Epitaxial Planar Transistor
BTB1238AM3

BV_{CEO}	-240V
I_C	-1A
$V_{CESAT(Max)}$	-0.3V

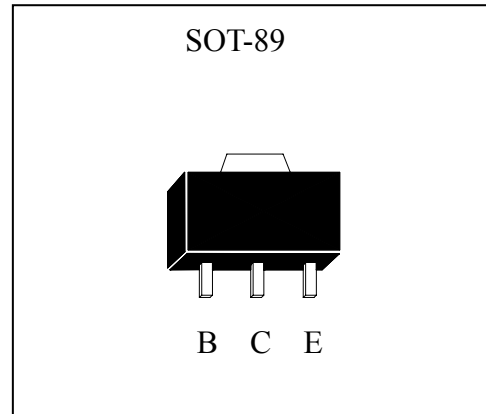
Description

- High BV_{CEO}
- High current capability
- Pb-free lead plating and halogen-free package

Symbol

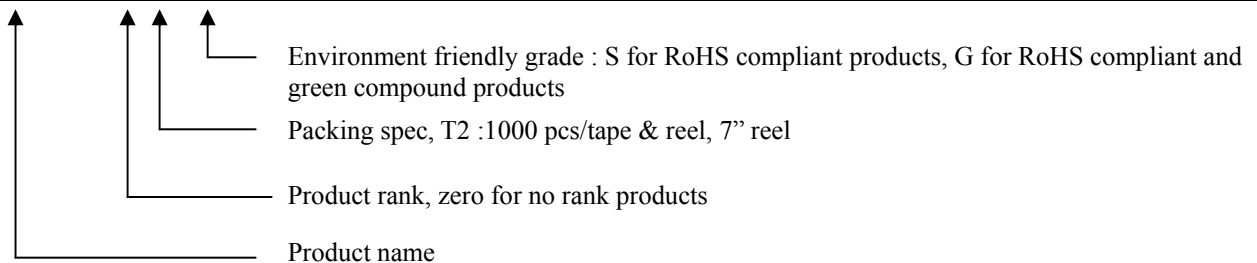


Outline



Ordering Information

Device	Package	Shipping
BTB1238AM3-X-T2-G	SOT-89 (Pb-free lead plating and halogen-free package)	1000 pcs / Tape & Reel





Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CBO}	-240	V
Collector-Emitter Voltage	V _{CEO}	-240	V
Emitter-Base Voltage	V _{EBO}	-7	V
Collector Current (DC)	I _C	-1	A
Collector Current (Pulse)	I _{CP}	-2 (Note 1)	A
Power Dissipation	P _D	0.6	W
		1 (Note 2)	W
		2 (Note 3)	W
Thermal Resistance, Junction to Ambient	R _{θJA}	208	°C/W
		125 (Note 2)	°C/W
		62.5 (Note 3)	°C/W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55~+150	°C

- Note : 1. Single Pulse Pw ≤ 300μs, Duty ≤ 2%.
 2. When mounted on FR-4 PCB with area measuring 10×10×1 mm.
 3. When mounted on ceramic with area measuring 40×40×1 mm

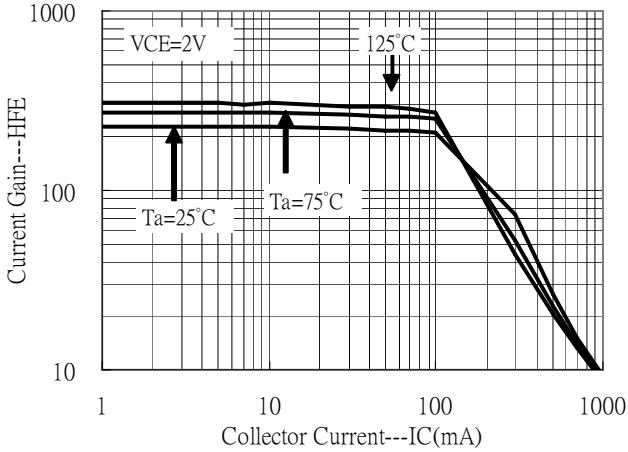
Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	-240	-	-	V	I _C =-50μA, I _E =0
BV _{CEO}	-240	-	-	V	I _C =-1mA, I _B =0
BV _{EBO}	-7	-	-	V	I _E =-50μA, I _C =0
I _{CBO}	-	-	-100	nA	V _{CB} =-240V, I _E =0
I _{EBO}	-	-	-100	nA	V _{EB} =-7V, I _C =0
*V _{CE(sat)}	-	-	-0.3	V	I _C =-500mA, I _B =-50mA
*V _{CE(sat)}	-	-	-3	V	I _C =-1A, I _B =-100mA
*V _{BE(sat)}	-	-	-1.1	V	I _C =-1A, I _B =-100mA
*V _{BE(on)}	-	-	-0.9	V	V _{CE} =-5V, I _C =-150mA
h _{FE1}	120	-	400	-	V _{CE} =-5V, I _C =-100mA
h _{FE2}	60	-	-	-	V _{CE} =-5V, I _C =-500mA
f _T	-	140	-	MHZ	V _{CE} =-5V, I _C =-150mA
Cob	-	27	-	pF	V _{CB} =-10V, I _E =0, f=1MHz

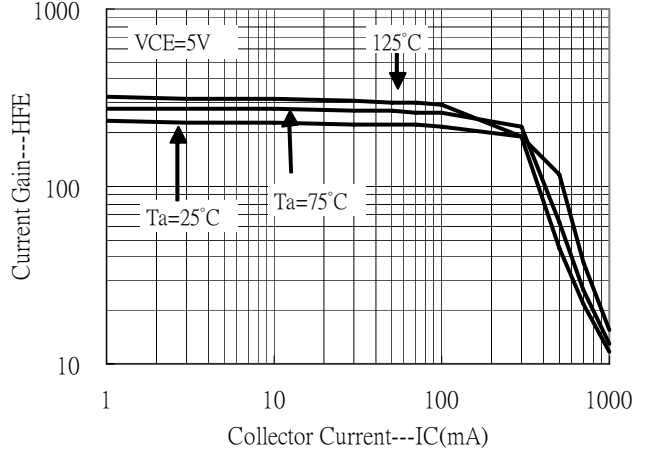
*Pulse Test: Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

Typical Characteristics

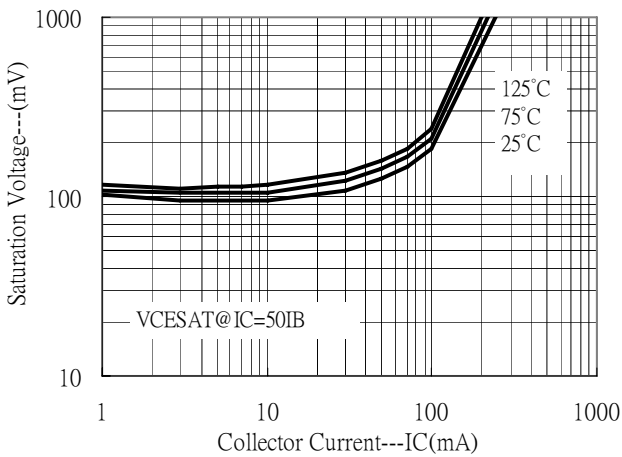
Current Gain vs Collector Current



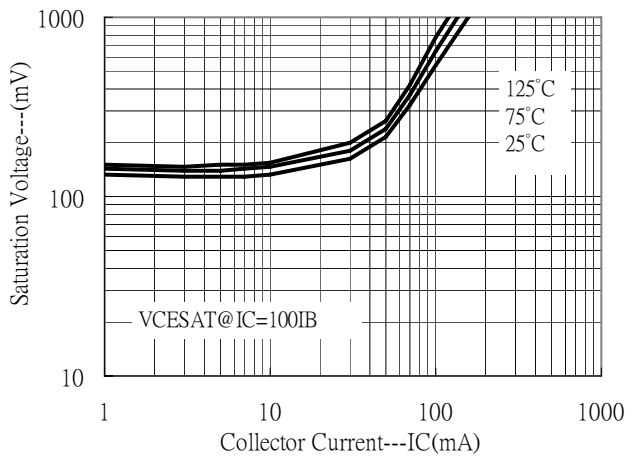
Current Gain vs Collector Current



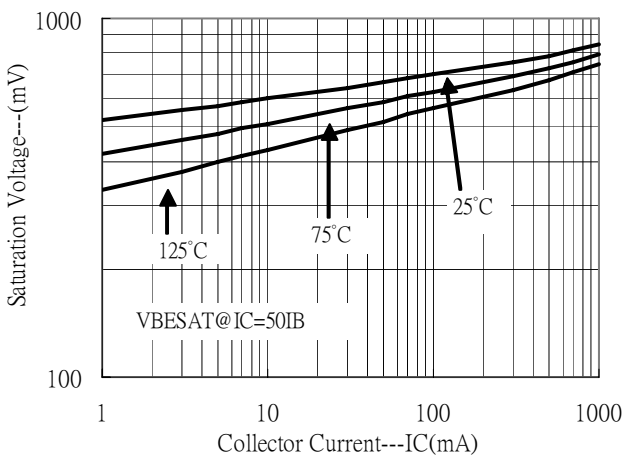
Saturation Voltage vs Collector Current



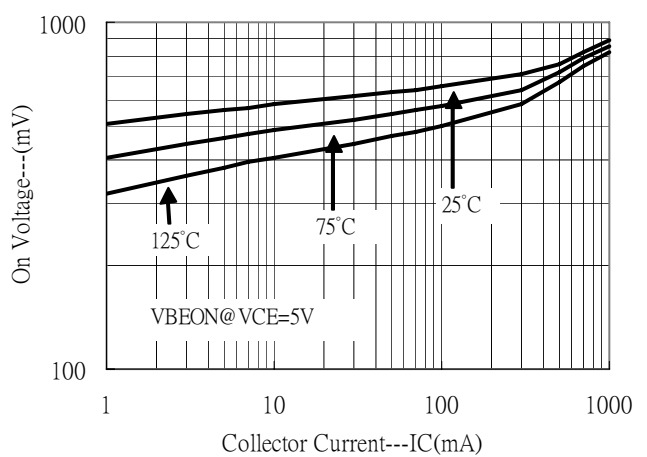
Saturation Voltage vs Collector Current



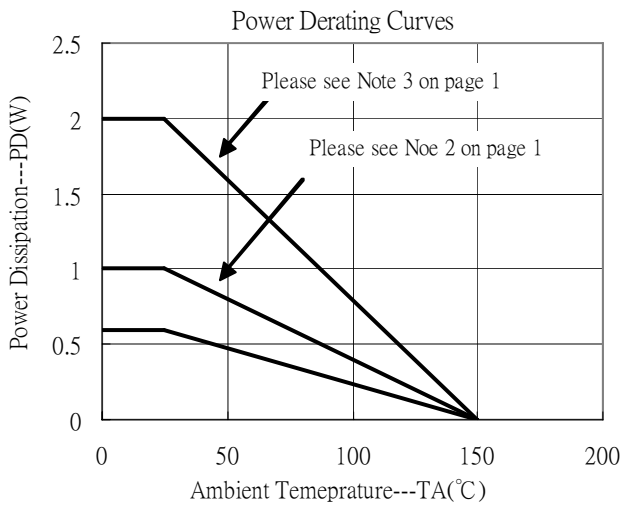
Saturation Voltage vs Collector Current



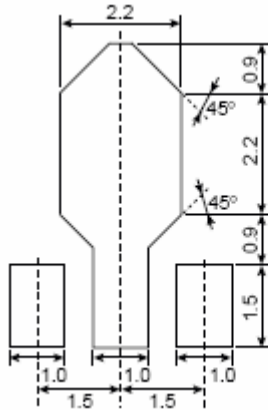
On Voltage vs Collector Current



Typical Characteristics(Cont.)

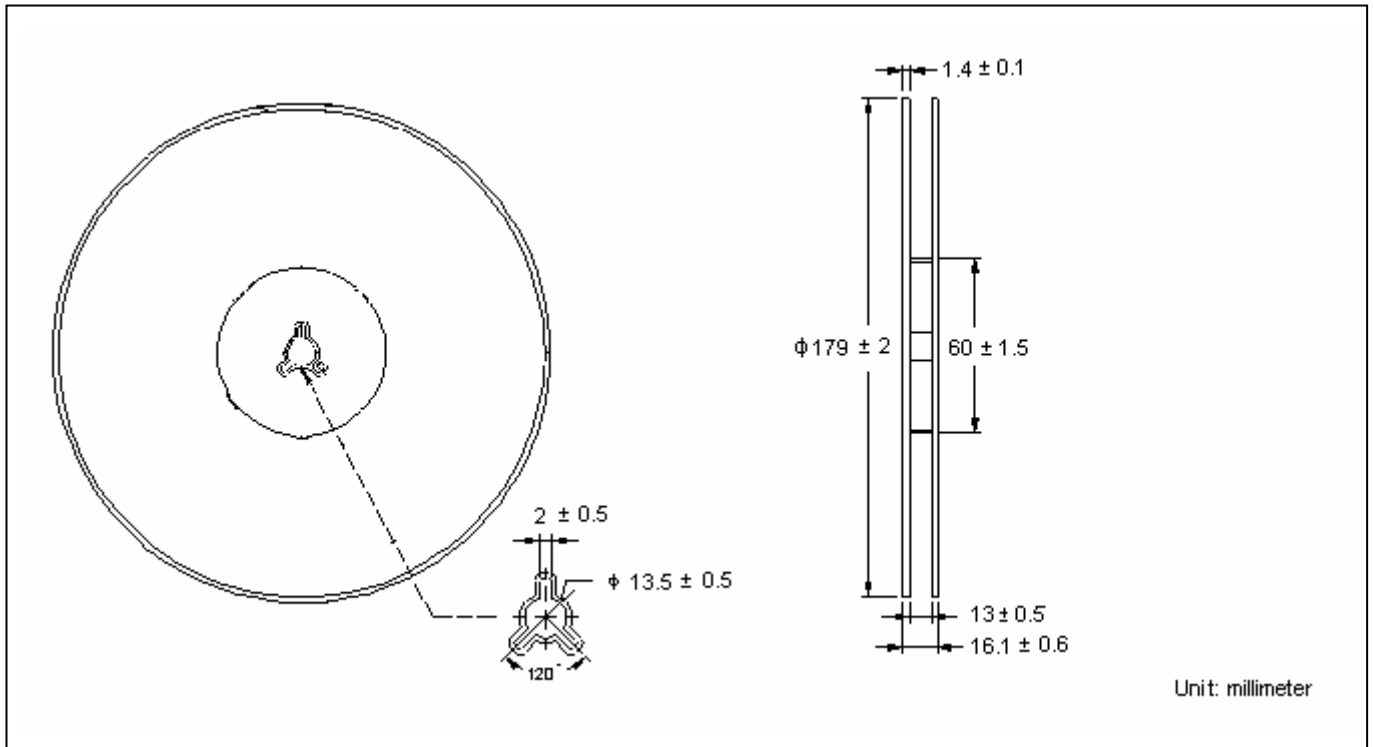


Recommended soldering footprint

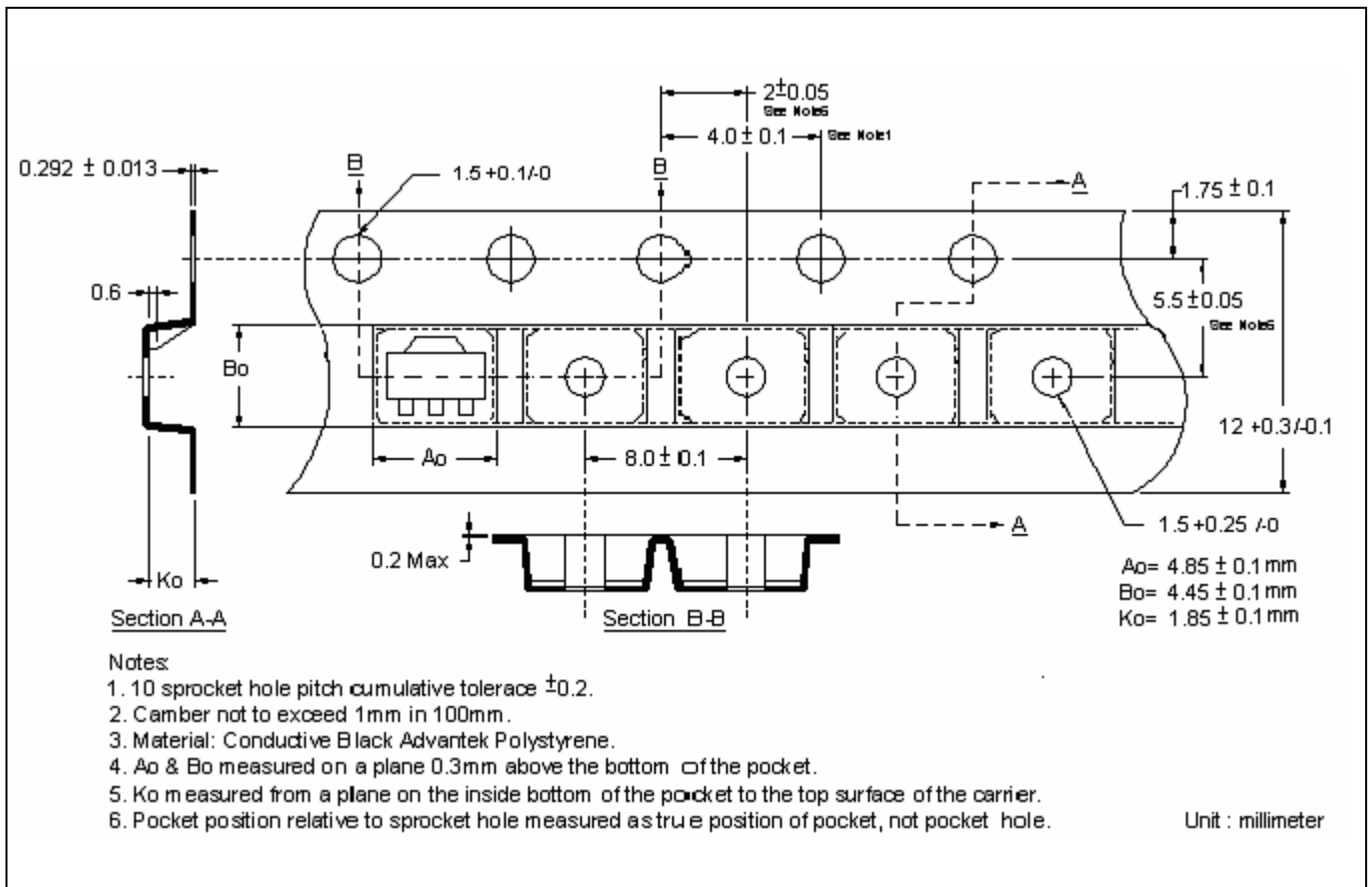


unit : mm

Reel Dimension

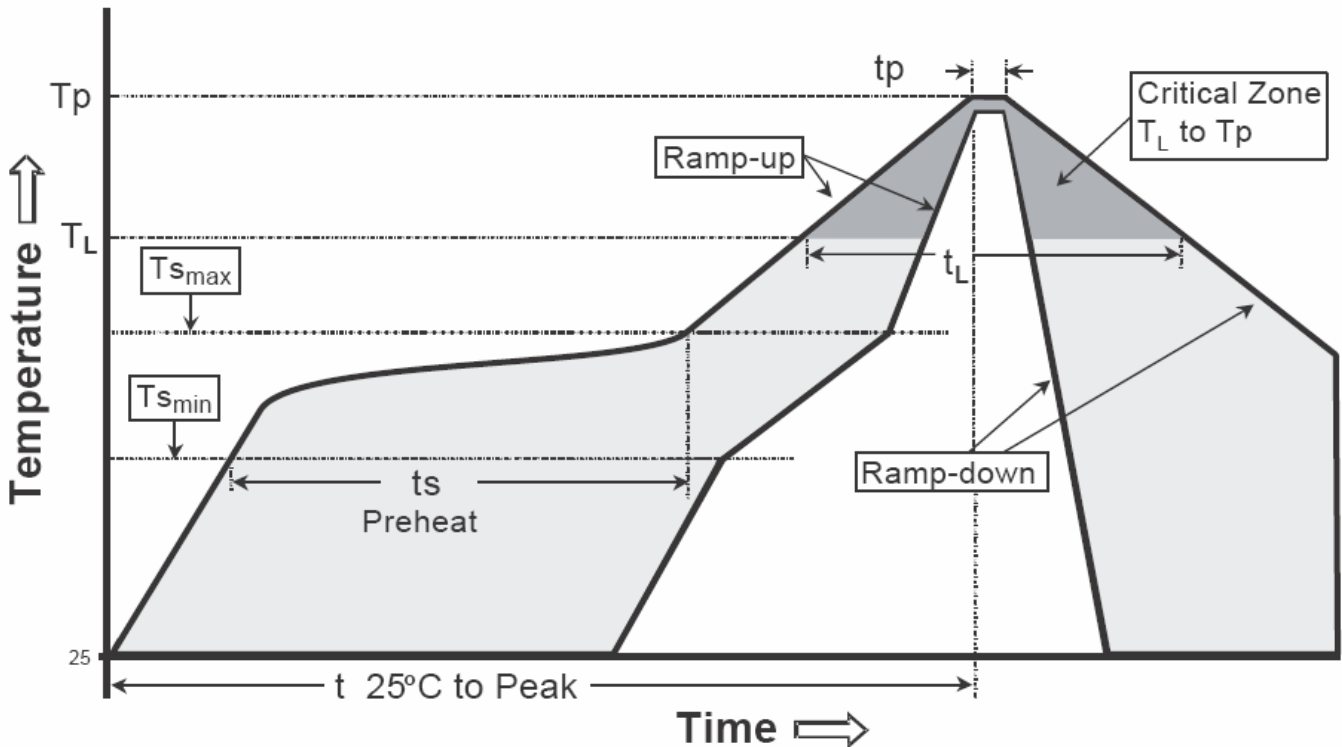


Carrier Tape Dimension



Recommended wave soldering condition

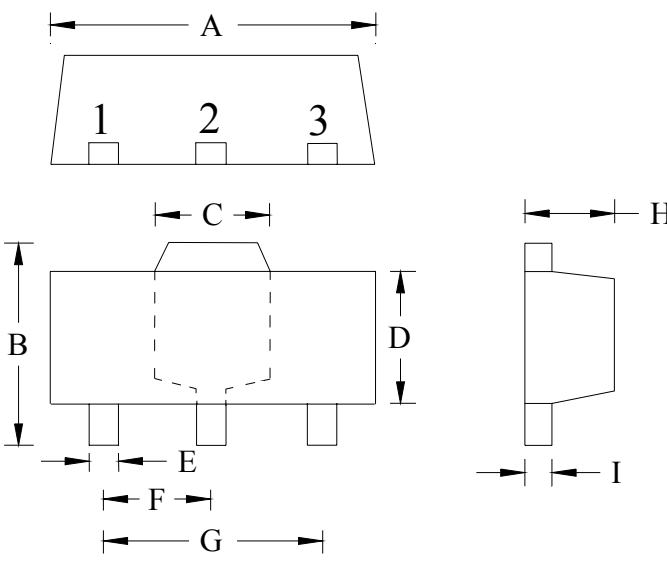
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow


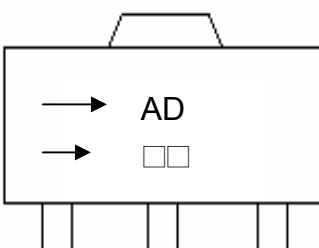
Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T_s min)	100°C	150°C
-Temperature Max(T_s max)	150°C	200°C
-Time($t_{s\ min}$ to $t_{s\ max}$)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T_L)	183°C	217°C
- Time (t_L)	60-150 seconds	60-150 seconds
Peak Temperature(T_P)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-89 Dimension



Marking:



Device Code → AD

Date Code → □ □

Style: Pin 1. Base 2. Collector 3. Emitter

3-Lead SOT-89 Plastic
 Surface Mounted Package
 CYStek Package Code: M3

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1732	0.1811	4.40	4.60	F	0.0591	TYP	1.50	TYP
B	0.1551	0.1673	3.94	4.25	G	0.1181	TYP	3.00	TYP
C	0.0610	REF	1.55	REF	H	0.0551	0.0630	1.40	1.60
D	0.0906	0.1024	2.30	2.60	I	0.0138	0.0173	0.35	0.44
E	0.0126	0.0205	0.32	0.52					

Notes: 1. Controlling dimension: millimeters.
 2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of CYStek.
- CYStek reserves the right to make changes to its products without notice.
- CYStek **semiconductor products are not warranted to be suitable for use in Life-Support Applications, or systems.**
- CYStek assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.